

Switchmode Dual Fast Recovery Power Rectifiers

Designed for use in switching power supplies. inverters and as free wheeling diodes. These state-of-the-art devices have the following

Features

- *Low Reverse Leakage Current
- *Fast Switching for High Efficiency
- *150°C Operating Junction Temperature
- *Low Stored Charge Majority Carrier Conduction
- *Low Forward Voltage, High Current Capability
- * Plastic Material used Carries Underwriters Laboratory Flammability Classification 94V-O
- * Pb free
- * In compliance with EU RoHs directives



MAXIMUM RATINGS

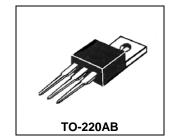
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Characteristic	Symbol	FE20C20C	Unit				
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	200	V				
RMS Reverse Voltage	$V_{R(RMS)}$	140	V				
Average Rectifier Forward Current (per diode) Total Device (Rated V _R)	I _{F(AV)}	10 20	А				
Peak Repetitive Forward Current (Rate V _R , Square Wave, 20kHz)	I _{FM}	20	Α				
Non-Repetitive Peak Surge Current (Surge applied at rate load conditions halfware, single phase, 60Hz)	I _{FSM}	125	А				
Operating and Storage Junction Temperature Range	T_J,T_stg	-65 to +150	$^{\circ}\!\!\!\!\!\!\!\!\!\!\!\!\!\!\!\!\!\!\!\!\!\!\!\!\!\!\!\!\!\!\!\!\!\!\!\!$				

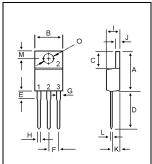
ELECTRICAL CHARACTERISTICS

ELECTRICAL CHARACTERIOTICS						
Characteristic	Symbol	Min.	Тур.	Max.	Unit	
Maximum Instantaneous Forward Voltage ($I_F = 10 \text{ Amp } T_C = 25^{\circ}C$) ($I_F = 10 \text{ Amp } T_C = 125^{\circ}C$)	V _F		0.92 0.78	1.3	٧	
Maximum Instantaneous Reverse Current (Rated DC Voltage, $T_C = 25^{\circ}C$) (Rated DC Voltage, $T_C = 125^{\circ}C$)	I _R		0.01 5	10 	uA	
Reverse Recovery Time ($I_F = 0.5 \text{ A}, I_R = 1.0, I_{rr} = 0.25 \text{ A}$)	T _{rr}			150	ns	
Typical Junction Capacitance (Reverse Voltage of 4 volts & f=1 MHz)	СР		65		₽F	

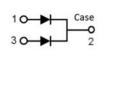
FAST RECOVERY RECTIFIERS

20 AMPERES 200 VOLTS

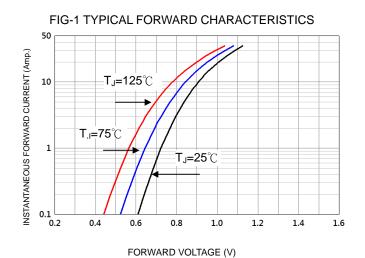


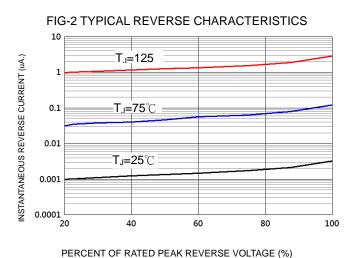


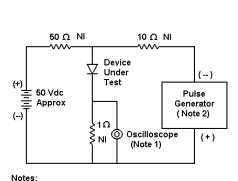
DIM	MILLIMETERS		
DIIVI	MIN	MAX	
Α	14.68	16.00	
В	9.78	10.42	
С	5.02	6.60	
D	13.00	14.62	
Е	3.10	4.19	
F	2.41	2.67	
G	1.10	1.67	
Н	0.69	1.01	
1	4.22	4.98	
J	1.14	1.40	
K	2.20	3.30	
L	0.28	0.61	
M	2.48	3.00	
0	3.50	4.00	



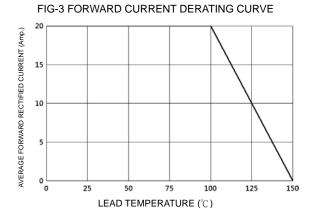


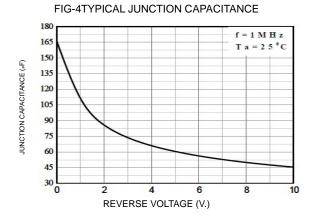


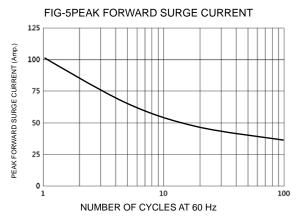


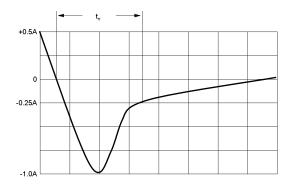


1. Rise Time = 7 ns max. Input Impedance =1 M Ω , 22 pF 2. Rise Time = 10 ns max. Input Impedance = 50 Ω









Set time base for 20/50 ns/cm

FIG-6 Reverse Recovery Time Characteristic and Test Circuit Diagram



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